

GLASS PASSIVATED RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 1.0 A

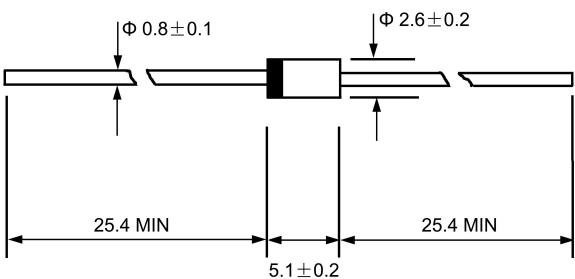
FEATURES

- ◇ Low cost
- ◇ Glass passivated junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC DO-41, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces, 0.34 grams
- ◇ Mounting position: Any

DO - 41



Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

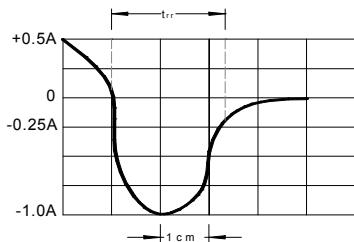
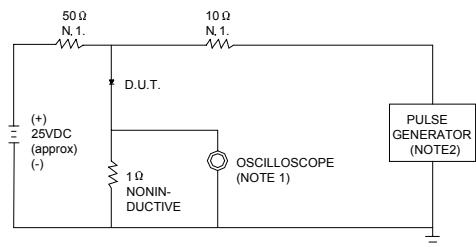
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		FR101G	FR102G	FR103G	FR104G	FR105G	FR106G	FR107G	UNITS				
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V				
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V				
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V				
Maximum average forward rectified current 9.5mm lead length, $\text{@ } T_A = 75^\circ\text{C}$	$I_{F(AV)}$	1.0							A				
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load $\text{@ } T_J = 125^\circ\text{C}$	I_{FSM}	30.0							A				
Maximum instantaneous forward voltage at 1.0A	V_F	1.3							V				
Maximum reverse current $\text{@ } T_A = 25^\circ\text{C}$ at rated DC blocking voltage $\text{@ } T_A = 100^\circ\text{C}$	I_R	5.0 100.0							μA				
Maximum reverse recovery time (Note1)	t_{rr}	150		250		500		ns					
Typical junction capacitance (Note2)	C_J	12.0							pF				
Typical thermal resistance (Note3)	$R_{\theta JA}$	55.0							$^\circ\text{C/W}$				
Operating junction temperature range	T_J	- 55 ---- + 175							$^\circ\text{C}$				
Storage temperature range	T_{STG}	- 55 ---- +175							$^\circ\text{C}$				

NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_n=0.25\text{A}$.

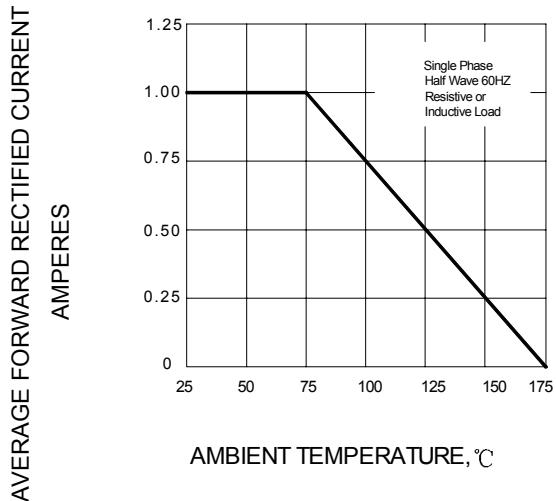
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

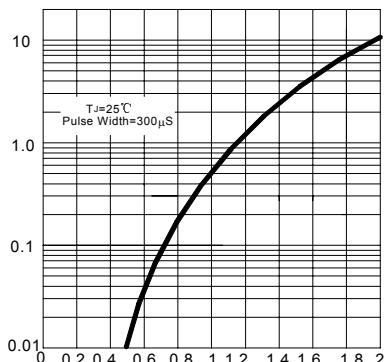
FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

NOTES:
 1.RISE TIME = 7ns MAX INPUT IMPEDANCE = $1\text{M}\Omega$. 22pF.
 2.RISE TIME =10ns MAX SOURCE IMPEDANCE=50 Ω .

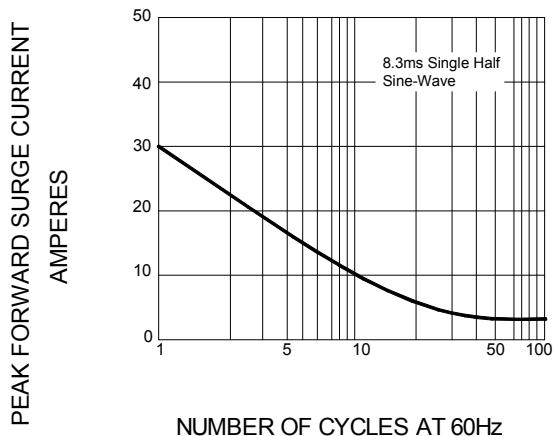
SET TIME BASE FOR 50/100 ns/cm

FIG.2 – TYPICAL FORWARD CURRENT DERATING CURVE

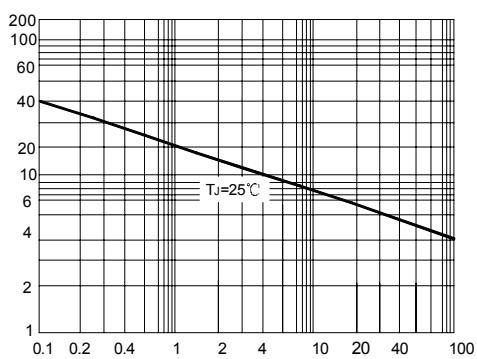
INSTANTANEOUS FORWARD CURRENT
AMPERES

FIG.3 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.4 – PEAK FORWARD SURGE CURRENT

JUNCTION CAPACITANCE, pF

FIG.5 – TYPICAL JUNCTION CAPACITANCE

REVERSE VOLTAGE, VOLTS